






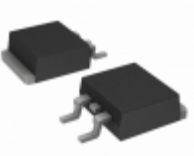
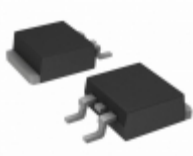


	<p>IRFBE30STRLPBF</p>
	<p>Hersteller-Teilenummer: IRFBE30STRLPBF</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 800V 4.1A D2PAK</p> <p>Datenblätter:  IRFBE30STRLPBF.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 9171 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	IRFBE30STRLPBF
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 800V 4.1A D2PAK
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs ,
Teilstatus	9171 pcs Stock
Serie	-
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	TO-263-3, D ² Pak (2 Leads + Tab), TO-263AB
Supplier Device-Gehäuse	D2PAK
Verlustleistung (max)	125W (Tc)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	800V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	4.1A (Tc)
Rds On (Max) @ Id, Vgs	3 Ohm @ 2.5A, 10V
VGS (th) (Max) @ Id	4V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	78nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	1300pF @ 25V
Verpackung	Tape & Reel (TR)



IRFBE30STRLPBF ist neu im Original, Suche IRFBE30STRLPBF Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie IRFBE30STRLPBF Vishay / Siliconix mit Garantie und Vertrauen. Anfrage IRFBE30STRLPBF: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>IRFBF20 Vishay / Siliconix MOSFET N-CH 900V 1.7A TO-220AB</p>	 <p>IRFBE30STRR Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBF20 Electro-Films (EFI) / Vishay MOSFET N-CH 900V 1.7A TO-220AB</p>	 <p>IRFBE30STRL Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A D2PAK</p>
 <p>IRFBE30STRL Vishay / Siliconix MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBE30STRR Vishay / Siliconix MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBE30SPBF Electro-Films (EFI) / Vishay MOSFET N-CH 800V 4.1A D2PAK</p>	 <p>IRFBF20L Vishay / Siliconix MOSFET N-CH 900V 1.7A TO-262</p>

heiße Teile

Mehr

 IRFBC40LCPBF	 IRFBC40LPBF	 IRFBC40LPBF	 IRFBC40S	 IRFBC40S
 IRFBC40SPBF	 IRFBC40SPBF	 IRFBC40STRL	 IRFBC40STRL	 IRFBC40STRLPBF
 IRFBC40STRLPBF	 IRFBC40STRR	 IRFBC40STRR	 IRFBC41LC	 IRFBE20PBF
 IRFBE20PBF	 IRFBE20SPBF	 IRFBE30L	 IRFBE30L	 IRFBE30LPBF-M
 IRFBE30PBF	 IRFBE30PBF	 IRFBE30SPBF	 IRFBE30SPBF	 IRFBE30STRLPBF
 IRFBF20LPBF	 IRFBF20LPBF	 IRFBE20STRL	 IRFBF20STRL	 IRFBF20STRLPBF
 IRFBF20STRLPBF	 IRFBG20PBF	 IRFBG20PBF	 IRFBG30PBF	 IRFBG30PBF
 IRFBL10N60A	 IRFC480LCD	 IRFD010PBF	 IRFD010PBF	 IRFD020PBF
 IRFD020PBF	 IRFD110PBF	 IRFD110PBF	 IRFD120PBF	 IRFD120PBF
 IRFD12N06RLESM	 IRFD210PBF	 IRFD210PBF	 IRFD214PBF	 IRFD214PBF

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